Micropower with high merit factor cmos operational amplifiers

Features

- Low supply voltage: 1.5 V – 5.5 V
- Rail-to-rail input and output
- Low input offset voltage: 800 µV max (A version)
- Low power consumption: 29 µA typical
- Gain bandwidth product: 1.3 MHz typical
- Stable when used in gain configuration
- Micropackages: SOT23-5, SC70-5
- Low input bias current: 1 pA typical
- Extended temperature range: -40 to 125 °C
- 4 kV human body model

Applications

- Battery-powered applications
- Portable devices
- Signal conditioning
- Active filtering
- Medical instrumentation

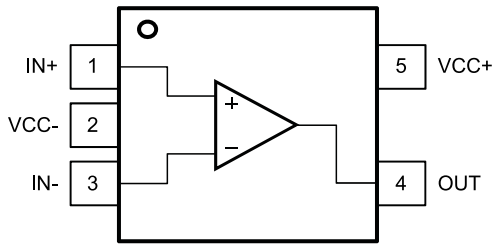
Description

The the TSV6291 are single operational amplifiers with a high bandwidth which consume only 29 µA. They must be used in a gain configuration (G < -3, G > 4).

With a very low input bias current and low offset voltage (800 µV maximum for the A version), the TSV629family of devices is ideal for applications requiring precision. The devices can operate at a power supply ranging from 1.5 to 5.5 V, and therefore suit battery-powered devices, extending battery life.

Package pin connections

Package pin connections (top view)



SOT23-5/SC70-5

Absolute maximum ratings and operating conditions

Absolute maximum ratings (AMR)

Symbol	Parameter		Value	Unit
V_{CC}	Supply voltage (1)		6	V
V_{id}	Differential input voltage (2)		$\pm V_{CC}$	
V_{in}	Input voltage (3)		(V_{CC-}) - 0.2 to (V_{CC+}) + 0.2	
I_{in}	Input current (4)		10	mA
$\overline{SHDN}$	Shutdown voltage (3)		(V_{CC-}) - 0.2 to (V_{CC+}) + 0.2	V
T_{stg}	Storage temperature		-65 to 150	°C
T_j	Maximum junction temperature		150	
R_{thja}	Thermal resistance junction-to-ambient (5)(6)	SOT23-5	250	°C/W
		SC70-5	205	

(1)All voltage values, except differential voltage, are with respect to network ground terminal.

(2)Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.

(3)V_{cc} - V_{in} must not exceed 6 V, V_{in} must not exceed 6 V.

(4)Input current must be limited by a resistor in series with the inputs.

(5)R_{th} are typical values.

(6)Short-circuits can cause excessive heating and destructive dissipation.

(7)Human body model: 100 pF discharged through a 1.5 kΩ resistor between two pins of the device, done for all couples of pin combinations with other pins floating.

(8)Machine mode: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω), done for all couples of pin combinations with other pins floating.

(9)Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to the ground.

Operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	1.5 to 5.5	V
V_{icm}	Common mode input voltage range	(V_{CC-}) - 0.1 to (V_{CC+}) + 0.1	
T_{oper}	Operating free air temperature range	-40 to 125	°C

Electrical characteristics

Electrical characteristics at (VCC+) = 1.8 V with (VCC-) = 0 V, Vicm = VCC/2, Tamb = 25 °C, and RL connected to VCC/2 (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Offset voltage	TSV6291			4	mV
		TSV6291A			0.8	
		$T_{min} < T_{op} < T_{max}$, TSV6291			6	
		$T_{min} < T_{op} < T_{max}$,TSV6291A			2	
DV_{io}	Input offset voltage drift			2		µV/°C
I_{io}	Input offset current, $V_{out} = V_{CC}/2$ (1)			1	10	pA
		$T_{min} < T_{op} < T_{max}$		1	100	
I_{ib}	Input bias current, $V_{out} = V_{CC}/2$ (1)			1	10	
		$T_{min} < T_{op} < T_{max}$		1	100	
CMR	Common mode rejection ratio, 20 log ($\Delta V_{ic}/\Delta V_{io}$)	0 V to 1.8 V, V_{out} = 0.9 V	53	74		dB
		$T_{min} < T_{op} < T_{max}$	51			
A_{vd}	Large signal voltage gain	R_L = 10 kΩ, V_{out} = 0.5 V to 1.3 V	78	95		
		$T_{min} < T_{op} < T_{max}$	73			
V_{OH}	High-level output voltage, $V_{OH} = V_{CC} - V_{out}$	R_L = 10 kΩ		5	35	mV
		$T_{min} < T_{op} < T_{max}$			50	
V_{OL}	Low-level output voltage	R_L = 10 kΩ		4	35	
		$T_{min} < T_{op} < T_{max}$			50	
I_{out}	Isink	V_{out} = 1.8 V	6	12		mA
		$T_{min} < T_{op} < T_{max}$	4			
	Isource	V_{out} = 0 V	6	10		
		$T_{min} < T_{op} < T_{max}$	4			
I_{CC}	Supply current (per operator)	No load, $V_{out} = V_{CC}/2$		25	31	µA
		$T_{min} < T_{op} < T_{max}$			33	
GBP	Gain bandwidth product	R_L = 10 kΩ, C_L = 100 pF		1.1		MHz
Gain	Minimum gain for stability	Phase margin = 60 °, R_f = 10 kΩ, R_L = 10 kΩ, C_L = 20 pF		4		V/V
				-3		
SR	Slew rate	R_L = 10 kΩ, C_L = 100 pF, Vout = 0.5 V to 1.3 V		0.33		V/µs

(VCC+) = 3.3 V, (VCC-) = 0 V, Vicm = VCC/2, Tamb = 25 °C, RL connected to VCC/2 (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{io}	Offset voltage	TSV6291			4	mV
		TSV6291A			0.8	
		$T_{min} < T_{op} < T_{max}$, TSV6291			6	
		$T_{min} < T_{op} < T_{max}$, TSV6291A			2	
DV_{io}	Input offset voltage drift			2		µV/°C
I_{io}	Input offset current (1)			1	10	pA
		$T_{min} < T_{op} < T_{max}$		1	100	
I_{ib}	Input bias current (1)			1	10	
		$T_{min} < T_{op} < T_{max}$		1	100	
CMR	Common mode rejection ratio, 20 log ($\Delta V_{ic}/\Delta V_{io}$)	0 V to 3.3 V, V_{out} = 1.65 V	57	79		dB
		$T_{min} < T_{op} < T_{max}$	53			
A_{vd}	Large signal voltage gain	R_L= 10 kΩ, V_{out} = 0.5 V to 2.8 V	81	98		
		$T_{min} < T_{op} < T_{max}$	76			
V_{OH}	High-level output voltage, $V_{OH} = V_{CC} - V_{out}$	R_L = 10 kΩ		5	35	mV
		$T_{min} < T_{op} < T_{max}$			50	
V_{OL}	Low-level output voltage	R_L = 10 kΩ		4	35	
		$T_{min} < T_{op} < T_{max}$			50	
I_{out}	Isink	V_{out} = 5 V	23	45		mA
		$T_{min} < T_{op} < T_{max}$	20			
	Isource	V_{out} = 0 V	23	38		
		$T_{min} < T_{op} < T_{max}$	20			
I_{CC}	Supply current (per operator)	No load, V_{out} = 2.5 V		26	33	µA
		$T_{min} < T_{op} < T_{max}$			35	
GBP	Gain bandwidth product	R_L = 10 kΩ, C_L = 100 pF		1.2		MHz
Gain	Minimum gain for stability	Phase margin = 60 °, R_f = 10 kΩ, R_L = 10 kΩ, C_L = 20 pF		4		V/V
				-3		
SR	Slew rate	R_L = 10 kΩ, C_L = 100 pF, V_{out} = 0.5 V to 2.8 V		0.4		V/µs

(VCC+) = 5 V, (VCC-) = 0 V, Vicm = VCC/2, Tamb = 25 °C, RL connected to VCC/2 (unless otherwise specified)

Symbol	Parameter		Min.	Typ.	Max.	Unit
V_{io}	Offset voltage	TSV6291			4	mV
		TSV6291A			0.8	
		$T_{min} < T_{op} < T_{max}$, TSV6291			6	
		$T_{min} < T_{op} < T_{max}$, TSV6291A			2	
DV_{io}	Input offset voltage drift			2		µV/°C
I_{io}	Input offset current (1)			1	10	pA
		$T_{min} < T_{op} < T_{max}$		1	100	
I_{ib}	Input bias current (1)			1	10	
		$T_{min} < T_{op} < T_{max}$		1	100	
CMR	Common mode rejection ratio, 20 log ($\Delta V_{ic}/\Delta V_{io}$)	0 V to 5 V, V_{out} = 2.5 V	60	80		dB
		$T_{min} < T_{op} < T_{max}$	55			
SVR	Supply voltage rejection ratio, 20 log ($\Delta V_{CC}/\Delta V_{io}$)	V_{CC} = 1.8 to 5 V	75	102		
		$T_{min} < T_{op} < T_{max}$	73			
A_{vd}	Large signal voltage gain	R_L = 10 kΩ, V_{out} = 0.5 V to 4.5 V	85	98		
		$T_{min} < T_{op} < T_{max}$	80			
V_{OH}	High-level output voltage, $V_{OH} = V_{CC} - V_{out}$	R_L = 10 kΩ		7	35	mV
		$T_{min} < T_{op} < T_{max}$			50	
V_{OL}	Low-level output voltage	R_L = 10 kΩ		6	35	
		$T_{min} < T_{op} < T_{max}$			50	
I_{out}	I_{sink}	V_{out} = 5 V	40	69		mA
		$T_{min} < T_{op} < T_{max}$	35			
	I_{source}	V_{out} = 0 V	40	74		
		$T_{min} < T_{op} < T_{max}$	35			
I_{CC}	Supply current (per operator)	No load, V_{out} = 2.5 V		30	36	µA
		$T_{min} < T_{op} < T_{max}$			38	
GBP	Gain bandwidth product	R_L = 10 kΩ, C_L = 100 pF		1.3		MHz
Gain	Minimum gain for stability	Phase margin = 60 °, R_f = 10 kΩ, R_L = 10 kΩ, C_L = 20 pF		4		V/V
				-3		
SR	Slew rate	R_L = 10 kΩ, C_L = 100 pF, V_{out} = 0.5 V to 4.5 V		0.5		V/µs
e_n	Equivalent input noise voltage	f = 1 kHz		70		nV/√Hz
THD	Total harmonic distortion	Av = -10, f_{in} = 1 kHz, R_L= 100 kΩ, V_{icm} = Vcc/2, V_{in} = 40 mVpp		0.15		%

Electrical characteristic curves

Figure 2: Supply current vs. supply voltage at Vicm = VCC/2

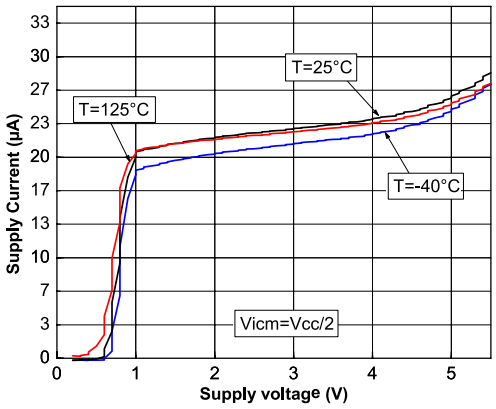


Figure 3: Output current vs. output voltage at VCC = 1.5 V

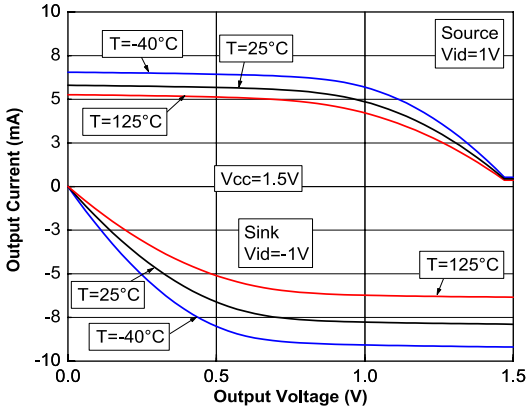


Figure 4: Output current vs. output voltage at VCC = 5 V

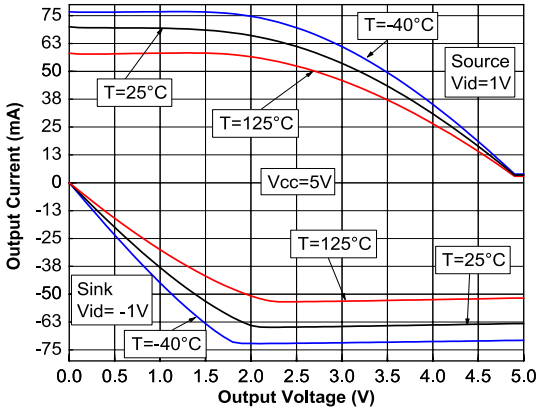


Figure 5: Peaking at closed loop gain = -10 at VCC = 1.5 V and VCC = 5 V

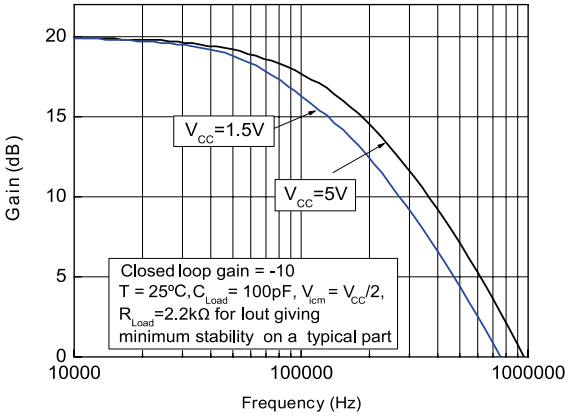


Figure 6: Peaking at closed loop gain = -3, VCC = 1.5 V

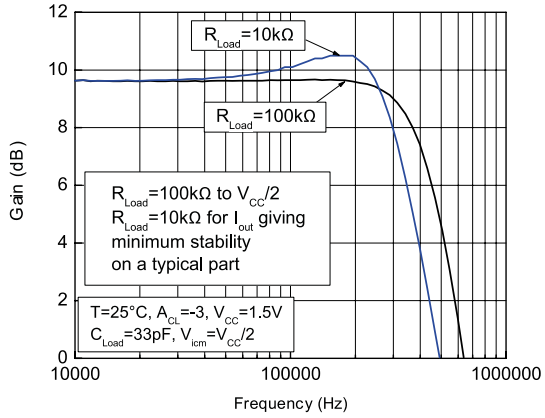


Figure 7: Peaking at closed loop gain = -3, VCC = 5 V

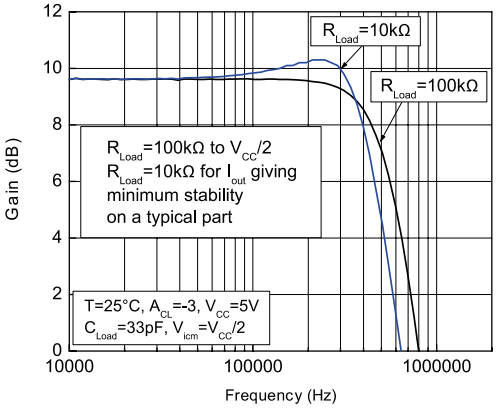


Figure 8: Positive slew rate vs. supply voltage in closed loop

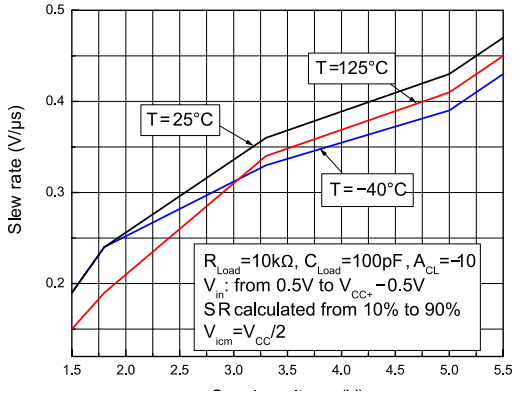


Figure 9: Negative slew rate vs. supply voltage in closed loop

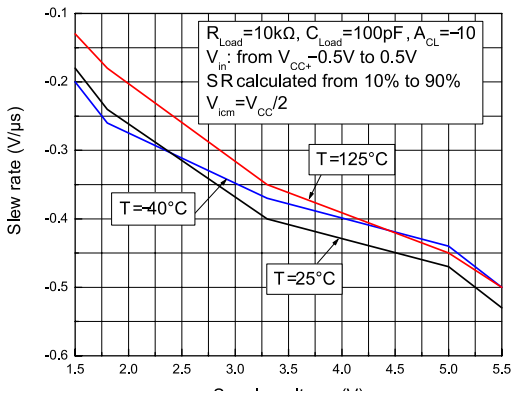


Figure 10: Slew rate vs. supply voltage in open loop

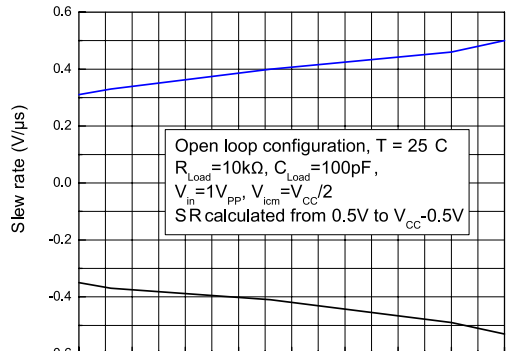


Figure 11: Slew rate timing in open loop

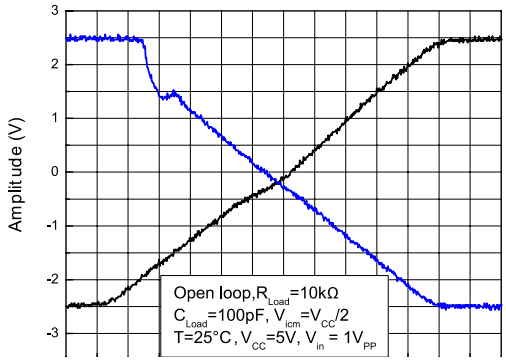


Figure 12: Slew rate timing in closed loop

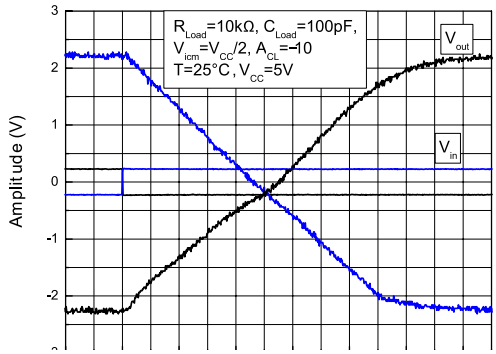


Figure 13: Noise at VCC = 5 V

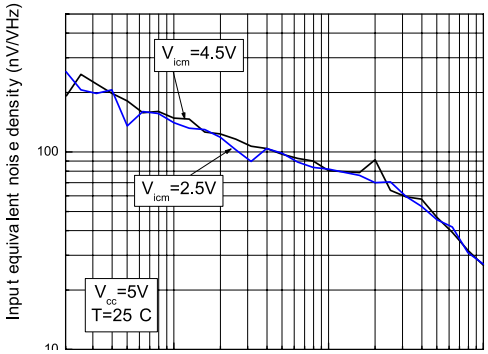


Figure 14: Distortion + noise vs. output voltage at VCC = 1.8 V

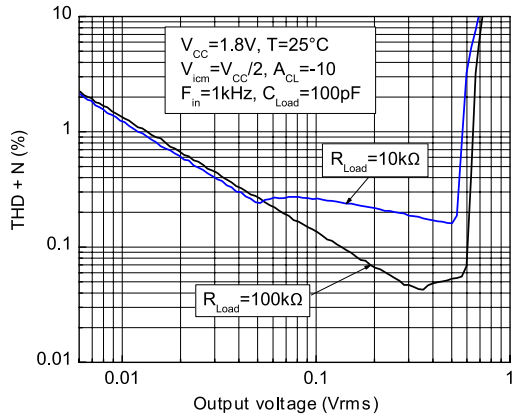


Figure 15: Distortion + noise vs. output voltage at VCC = 5 V

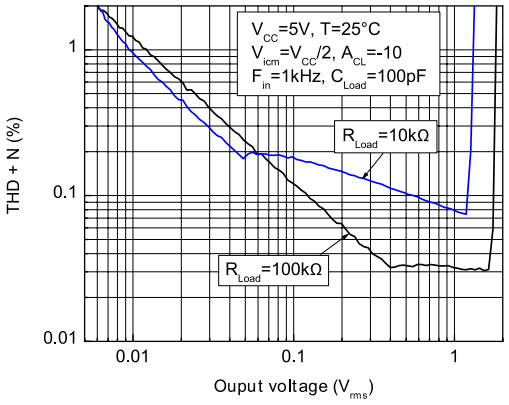


Figure 16: Distortion + noise vs. frequency at VCC = 1.8 V

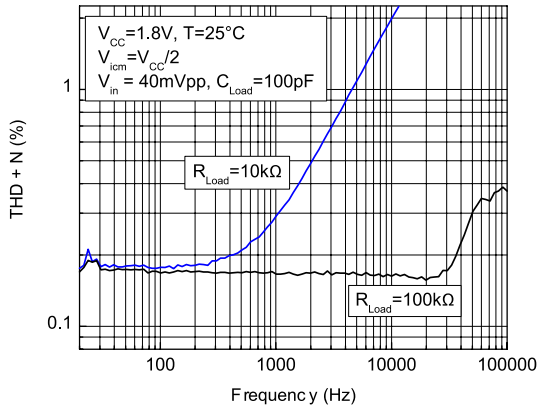


Figure 17: Distortion + noise vs. frequency at VCC = 5 V

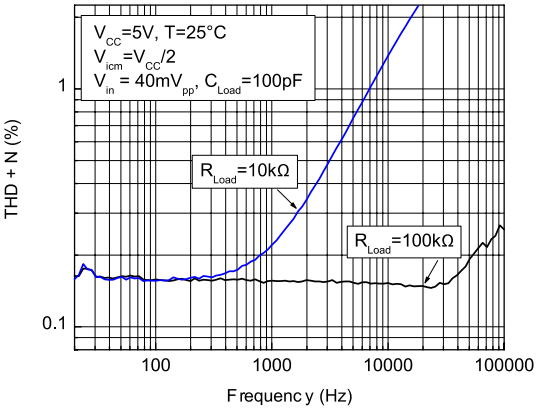


Figure 18: Input offset voltage vs. input common mode at VCC = 1.5 V

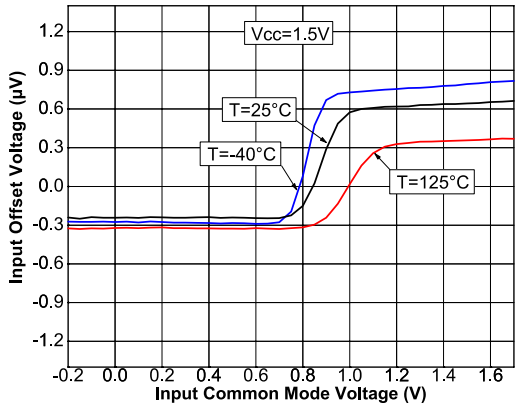


Figure 19: Input offset voltage vs. input common mode at VCC = 5 V

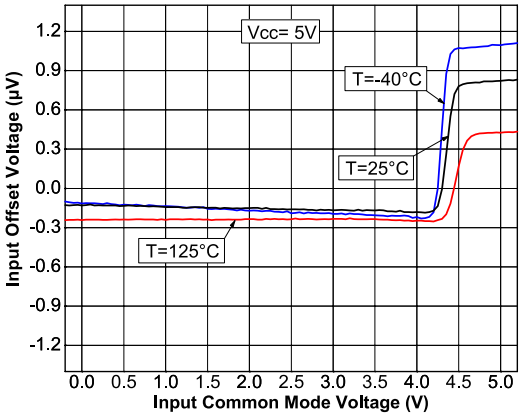


Figure 20: Test configuration for turn-on time
(Vout pulled down)

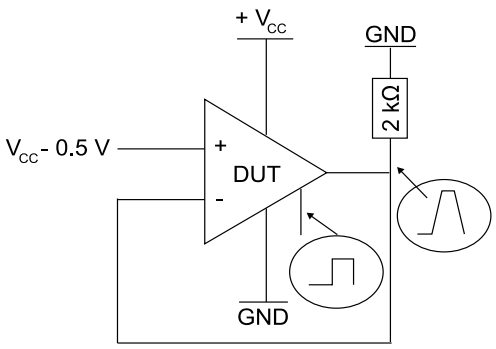


Figure 21: Test configuration for turn-off time
(Vout pulled down)

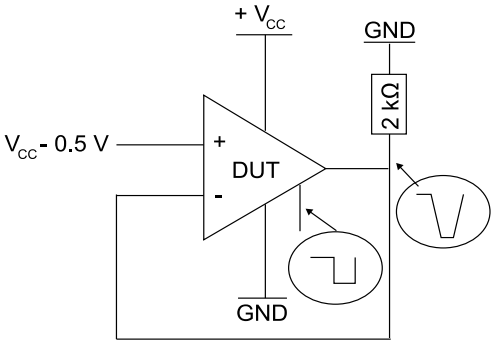


Figure 22: Turn-on time, VCC = 5 V, Vout pulled down,
T = 25 °C

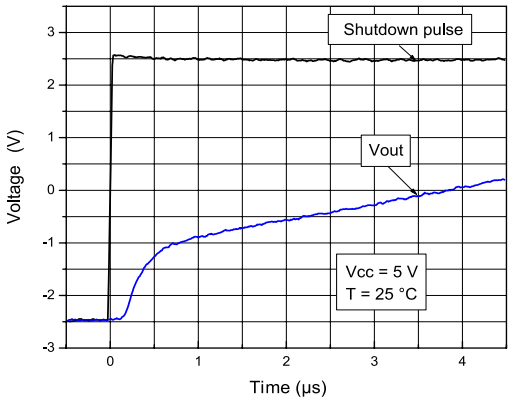
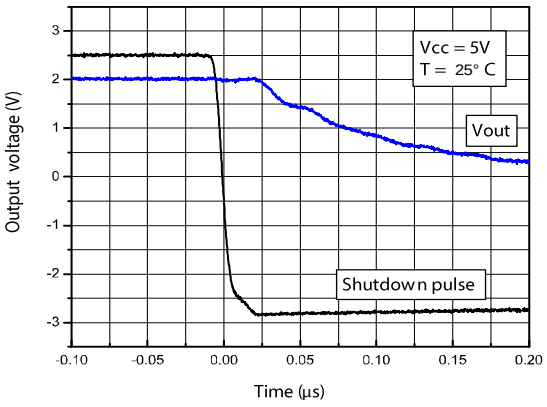
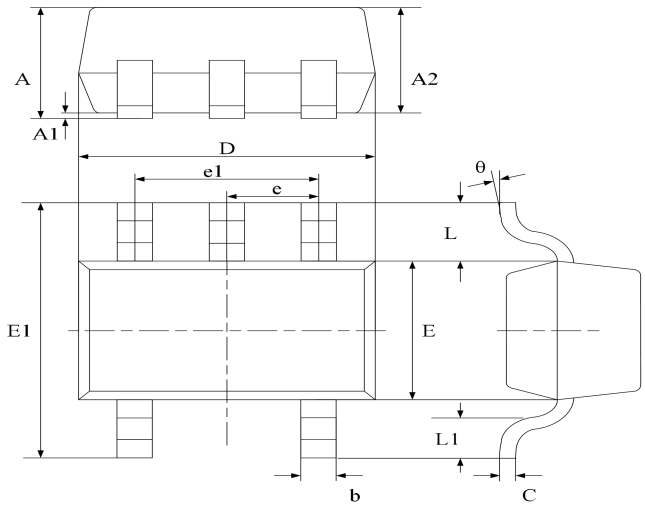


Figure 23: Turn-off time, VCC= 5 V, Vout pulled down,
T = 25 °C



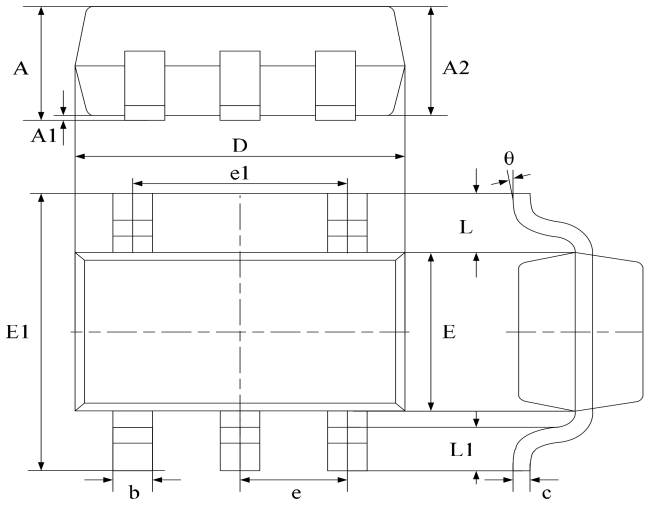
Package Information

SC70-5（SOT353）



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.800	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.035	0.039
b	0.150	0.350	0.006	0.014
C	0.080	0.150	0.003	0.006
D	1.8500	2.150	0.079	0.087
E	1.100	1.400	0.045	0.053
E1	1.950	2.200	0.085	0.096
e	0.850 typ.		0.026 typ.	
e1	1.200	1.400	0.047	0.055
L	0.42 ref.		0.021 ref.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT23-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.040	1.350	0.042	0.055
A1	0.040	0.150	0.002	0.006
A2	1.000	1.200	0.041	0.049
b	0.380	0.480	0.015	0.020
c	0.110	0.210	0.004	0.009
D	2.720	3.120	0.111	0.127
E	1.400	1.800	0.057	0.073
E1	2.600	3.000	0.106	0.122
e	0.950 typ.		0.037 typ.	
e1	1.900 typ.		0.078 typ.	
L	0.700 ref.		0.028 ref.	
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

Ordering information

Order code	Package	Baseqty	Deliverymode	Marking
UMW TSV6291AILT	SOT23-5	3000	Tape and reel	K113 U
UMW TSV6291ILT	SOT23-5	3000	Tape and reel	K107 U
UMW TSV6291AICT	SC70-5	3000	Tape and reel	K15 U

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